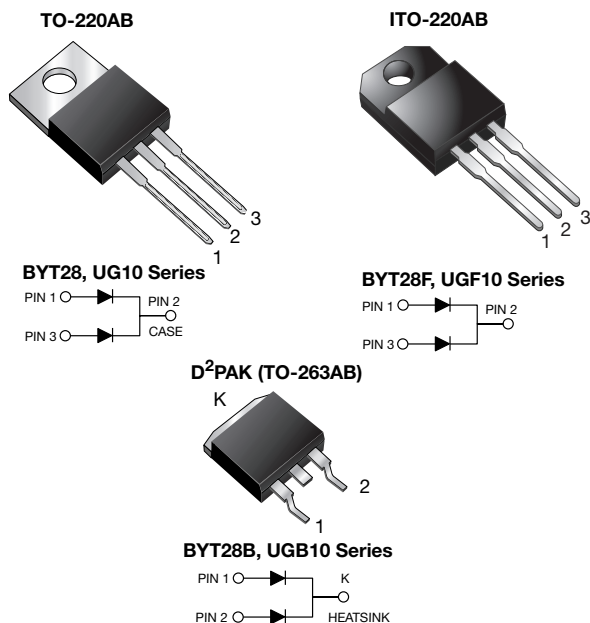




## Dual Common Cathode Ultrafast Soft Recovery Rectifier

RoHS  
COMPLIANT

### FEATURES

- Power pack
- Glass passivated pellet chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3 (for ITO-220AB and D<sup>2</sup>PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

### LINKS TO ADDITIONAL RESOURCES



3D Models

| PRIMARY CHARACTERISTICS |                                                    |
|-------------------------|----------------------------------------------------|
| $I_{F(AV)}$             | 2 x 5.0 A                                          |
| $V_{RRM}$               | 300 V to 400 V                                     |
| $I_{FSM}$               | 60 A                                               |
| $t_{rr}$                | 35 ns                                              |
| $V_F$                   | 1.05 V                                             |
| $T_J$ max.              | 150 °C                                             |
| Package                 | TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB) |
| Circuit configurations  | Common cathode                                     |

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade  
Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B,...)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)                                     |                                   |                      |                      |      |
|-----------------------------------------------------------------------------------------------------|-----------------------------------|----------------------|----------------------|------|
| PARAMETER                                                                                           | SYMBOL                            | BYT28-300<br>UG10FCT | BYT28-400<br>UG10GCT | UNIT |
| Maximum repetitive peak reverse voltage                                                             | V <sub>RRM</sub>                  | 300                  | 400                  | V    |
| Maximum working reverse voltage                                                                     | V <sub>RWM</sub>                  | 300                  | 400                  | V    |
| Maximum RMS voltage                                                                                 | V <sub>RMS</sub>                  | 210                  | 280                  | V    |
| Maximum DC blocking voltage                                                                         | V <sub>DC</sub>                   | 300                  | 400                  | V    |
| Maximum average forward rectified current at T <sub>C</sub> = 100 °C —<br>total device<br>per diode | I <sub>F(AV)</sub>                | 10                   |                      | A    |
|                                                                                                     |                                   | 5.0                  |                      |      |
| Peak forward surge current 8.3 ms single half sine-wave<br>superimposed on rated load per diode     | I <sub>FSM</sub>                  | 60                   |                      | A    |
| Operating junction and storage temperature range                                                    | T <sub>J</sub> , T <sub>STG</sub> | -40 to +150          |                      | °C   |
| Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min                              | V <sub>AC</sub>                   | 1500                 |                      | V    |



| ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |                                                                                                        |                         |                               |       |      |
|----------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|-------------------------|-------------------------------|-------|------|
| PARAMETER                                                                  | TEST CONDITIONS                                                                                        |                         | SYMBOL                        | VALUE | UNIT |
| Maximum instantaneous forward voltage per diode                            | I <sub>F</sub> = 5 A                                                                                   | T <sub>J</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 1.30  | V    |
|                                                                            | I <sub>F</sub> = 10 A                                                                                  |                         |                               | 1.40  |      |
|                                                                            | I <sub>F</sub> = 5 A                                                                                   | T <sub>J</sub> = 150 °C |                               | 1.05  |      |
| Maximum reverse current per diode at V <sub>RRM</sub>                      |                                                                                                        |                         | I <sub>R</sub>                | 10    | μA   |
|                                                                            |                                                                                                        |                         |                               | 200   |      |
| Maximum reverse recovery time per diode                                    | I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A                               |                         | t <sub>rr</sub>               | 35    | ns   |
|                                                                            | I <sub>F</sub> = 1.0 A, dI/dt = 100 A/μs, V <sub>R</sub> = 30 V, I <sub>rr</sub> = 0.1 I <sub>RM</sub> |                         |                               | 50    |      |
| Maximum reverse recovery current per diode                                 | I <sub>F</sub> = 5 A, dI/dt = 50 A/μs, V <sub>R</sub> = 30 V, T <sub>C</sub> = 100 °C                  |                         | I <sub>RM</sub>               | 3.0   | A    |
| Maximum stored charge per diode                                            | I <sub>F</sub> = 2 A, dI/dt = 20 A/μs, V <sub>R</sub> = 30 V, I <sub>rr</sub> = 0.1 I <sub>RM</sub>    |                         | Q <sub>rr</sub>               | 50    | nC   |

**Note**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS ( $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted) |                 |               |                 |                 |                             |
|--------------------------------------------------------------------------------------|-----------------|---------------|-----------------|-----------------|-----------------------------|
| PARAMETER                                                                            | SYMBOL          | BYT28<br>UG10 | BYT28F<br>UGF10 | BYT28B<br>UGB10 | UNIT                        |
| Typical thermal resistance junction to case per diode                                | $R_{\theta JC}$ | 4.5           | 6.7             | 4.5             | $^{\circ}\text{C}/\text{W}$ |

| ORDERING INFORMATION (Example) |                                  |                 |              |               |               |
|--------------------------------|----------------------------------|-----------------|--------------|---------------|---------------|
| PACKAGE                        | PREFERRED P/N                    | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
| TO-220AB                       | BYT28-400-E3/45                  | 1.80            | 45           | 50/tube       | Tube          |
| ITO-220AB                      | BYT28F-400-E3/45                 | 1.95            | 45           | 50/tube       | Tube          |
| TO-263AB                       | BYT28B-400-E3/45                 | 1.77            | 45           | 50/tube       | Tube          |
| TO-263AB                       | BYT28B-400-E3/81                 | 1.77            | 81           | 800/reel      | Tape and reel |
| ITO-220AB                      | BYT28F-400HE3_A/P <sup>(1)</sup> | 1.95            | P            | 50/tube       | Tube          |
| TO-263AB                       | BYT28B-400HE3_A/P <sup>(1)</sup> | 1.77            | P            | 50/tube       | Tube          |
| TO-263AB                       | BYT28B-400HE3_A/I <sup>(1)</sup> | 1.77            | I            | 800/reel      | Tape and reel |

**Note**

(1) AEC-Q101 qualified, available in ITO-220AB and TO-263AB package

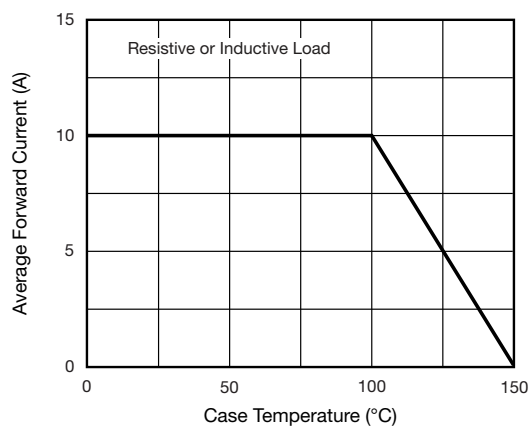
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Forward Current Derating Curve

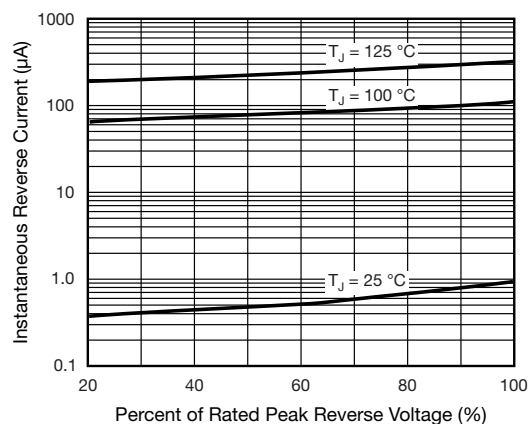


Fig. 4 - Typical Reverse Characteristics Per Diode

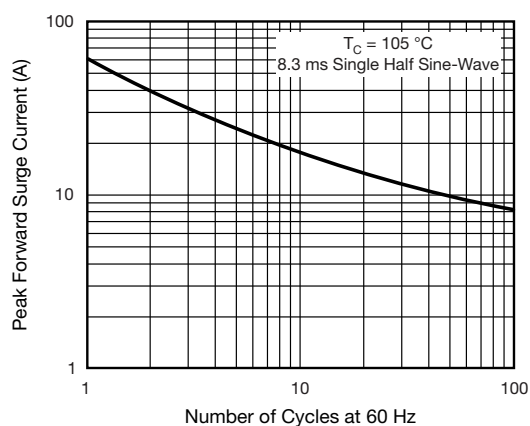


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

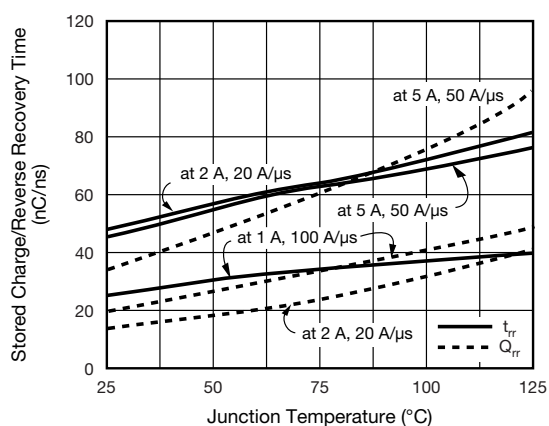


Fig. 5 - Reverse Switching Characteristics Per Diode

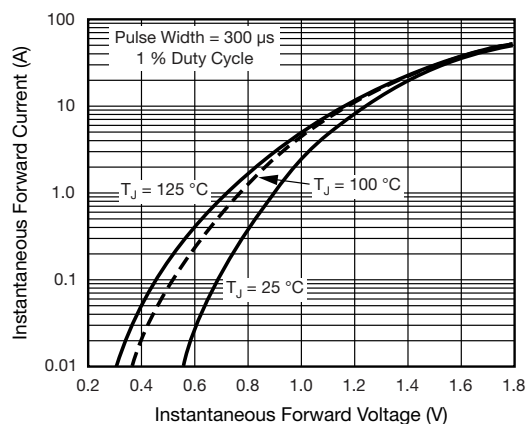


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

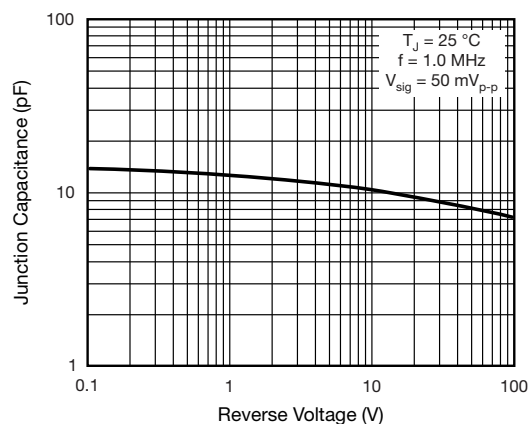
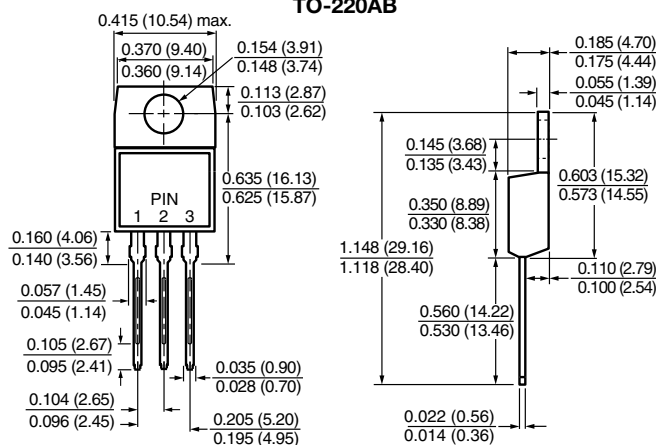
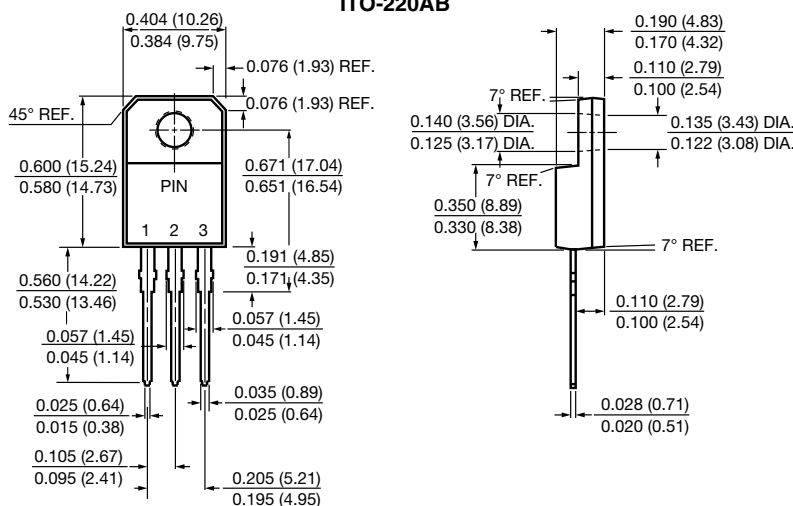
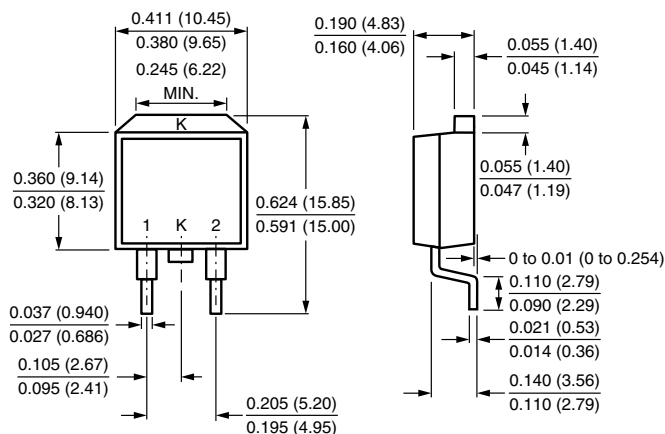
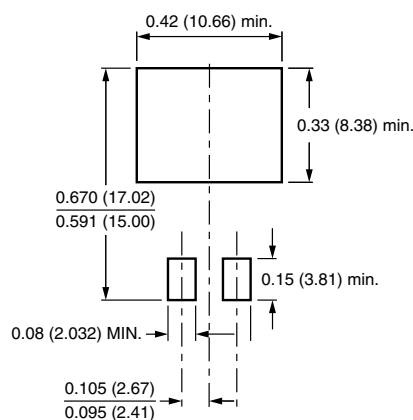


Fig. 6 - Typical Junction Capacitance Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)**TO-220AB****ITO-220AB****D<sup>2</sup>PAK (TO-263AB)****Mounting Pad Layout**



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